Small Signal MOSFET

60 V, 310 mA, Dual N-Channel with ESD Protection, SOT-563

Features

- Low R_{DS(on)} Improving System Efficiency
- Low Threshold Voltage
- ESD Protected Gate
- Small Footprint 1.6 x 1.6 mm
- These are Pb–Free Devices

Applications

- Load/Power Switches
- Driver Circuits: Relays, Lamps, Displays, Memories, etc.
- Battery Management/Battery Operated Systems
- Cell Phones, Digital Cameras, PDAs, Pagers, etc.

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted.)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage		V _{DSS}	60	V	
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	$T_A = 25^{\circ}C$	۱ _D	294	mA
Current (Note 1)	State	$T_A = 85^{\circ}C$		212	
Power Dissipation (Note 1)	Steady State		PD	250	mW
Continuous Drain	+~ E o	$T_A = 25^{\circ}C$	۱ _D	310	mA
Current (Note 1)	t≤5 s	$T_A = 85^{\circ}C$		225	
Power Dissipation (Note 1)	t ≤ 5 s		P _D	280	mW
Pulsed Drain Current	t _p = 10 μs		I _{DM}	590	mA
Operating Junction and Storage Temperature		T _J , T _{STG}	–55 to 150	°C	
Source Current (Body Diode)		۱ _S	350	mA	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	
Gate-Source ESD Rating (HBM, Method 3015)		ESD	900	V	

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	500	°C/W
Junction-to-Ambient – t \leq 5 s (Note 1)		447	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

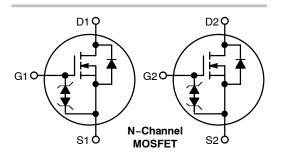
- 1. Surface mounted on FR4 board using 1 in sq pad size
 - (Cu. area = 1.127 in sq [1 oz] including traces).



ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D Max	
60	1.6 Ω @ 10 V	310 mA	
	2.5 Ω @ 4.5 V	310 IIIA	

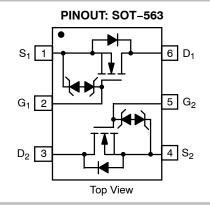






MARKING

S7 = Specific Device Code D = Date Code



ORDERING INFORMATION

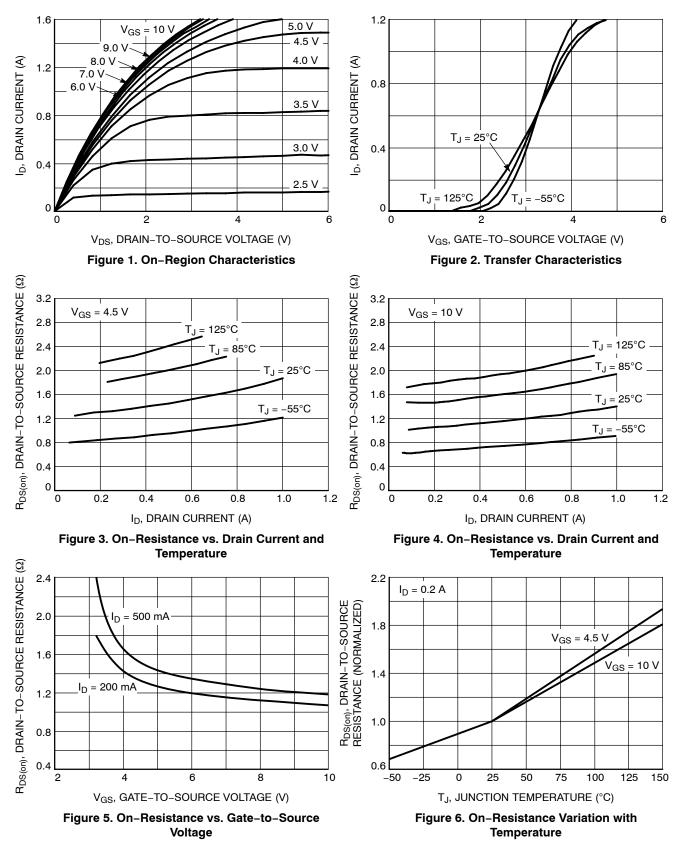
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted.)

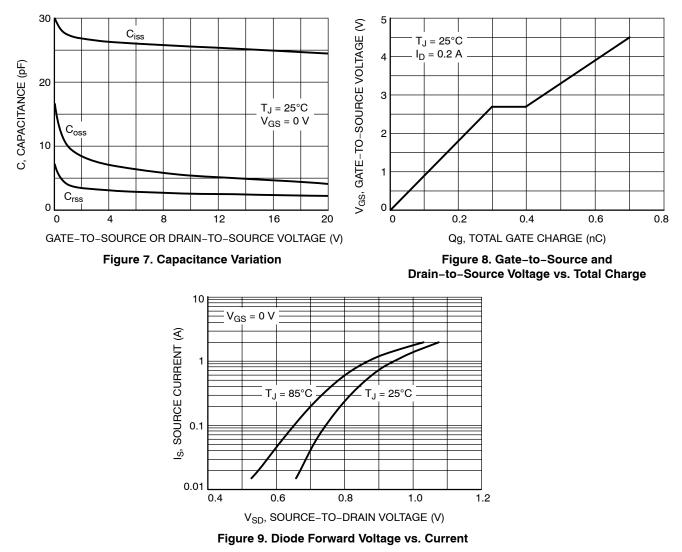
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							•
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D =	V_{GS} = 0 V, I_{D} = 250 μ A		-	-	V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	_	-		71	-	mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V V _{DS} = 60 V	$T_J = 25^{\circ}C$	-	-	1.0	μΑ
			T _J = 125°C	-	-	500	1
		V _{GS} = 0 V V _{DS} = 50 V	T _J = 25°C	-	-	100	nA
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	±10	μA
		V_{DS} = 0 V, V_{GS}	= ±10 V	-	-	450	nA
		V_{DS} = 0 V, V_{GS}	V_{DS} = 0 V, V_{GS} = ± 5.0 V		-	150	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$		1.0	-	2.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	_	-		4.0	-	mV/°C
Drain-to-Source On Resistance	$R_{DS(on)} = \frac{V_{GS} = 10 \text{ V}, \text{ I}_{D} = 500 \text{ mA}}{V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}}$	$V_{GS} = 10 \text{ V}, \text{ I}_{D} =$	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 500 \text{ mA}$		1.19	1.6	Ω
		= 200 mA	-	1.33	2.5		
Forward Transconductance	g fs	V_{DS} = 5.0 V, I_{D} = 200 mA		-	80	-	S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = 20 V		-	24.5	-	pF
Output Capacitance	C _{OSS}			-	4.2	-	
Reverse Transfer Capacitance	C _{RSS}			-	2.2	-	
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 10 V;		-	0.7	-	nC
Threshold Gate Charge	Q _{G(TH)}			-	0.1	-	
Gate-to-Source Charge	Q _{GS}	I _D = 200 r	πA	-	0.3	-	
Gate-to-Drain Charge	Q _{GD}			-	0.1	-	
SWITCHING CHARACTERISTICS (Note 4)							
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DD} = 30 V, I _D = 200 mA, R _G = 10 Ω		-	12	-	ns
Rise Time	tr			-	7.3	-	
Turn-Off Delay Time	t _{d(OFF)}			-	63.7	-]
Fall Time	t _f			-	30.6	-	
DRAIN-SOURCE DIODE CHARACTERISTIC	S						
Forward Diode Voltage	N	$V_{\rm GS} = 0 \rm V,$	$T_J = 25^{\circ}C$	-	0.8	1.2	V
	V _{SD}	I _S = 200 mÅ	T _J = 85°C	-	0.7	-	

Surface-mounted on FR4 board using 1 in. sq. pad size (Cu. area = 1.127 in sq [1 oz] including traces).
Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS







ORDERING INFORMATION

Device	Package	Shipping
NTZD5110NT1	SOT-563	3000 / Tape & Reel
NTZD5110NT1G	SOT-563 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOT-563, 6 LEAD

CASE 463A-01 **ISSUE D**

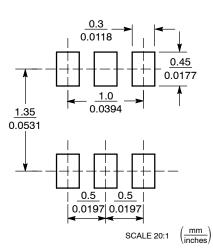
κ

NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS 1.

3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.50	1.70	0.059	0.067	
в	1.10	1.30	0.043	0.051	
С	0.50	0.60	0.020	0.024	
D	0.17	0.27	0.007	0.011	
G	0.50 BSC		0.020	BSC	
L	0.08	0.18	0.003	0.007	
K	0.10	0.30	0.004	0.012	
S	1.50	1.70	0.059	0.067	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

4

G

R

D 6 PI

Ф

0.08 (0.003) 🕅

X Y

> N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative